DATA SHEET

BB901
VHF variable capacitance diode

Product specification
Supersedes data of November 1993
File under Discrete Semiconductors, SC01

1996 May 03
VHF variable capacitance diode BB901

FEATURES

• Excellent linearity
• Small plastic SMD package
• C28: 1 pF; ratio: 13.5

APPLICATIONS

• Electronic tuning in satellite tuners
• Tunable coupling
• VCO.

DESCRIPTION

The BB901 is a variable capacitance diode, fabricated in planar technology, and encapsulated in the SOT23 small plastic SMD package.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

<table>
<thead>
<tr>
<th>SYMBOL</th>
<th>PARAMETER</th>
<th>MIN.</th>
<th>MAX.</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>V_R</td>
<td>continuous reverse voltage</td>
<td>–</td>
<td>28</td>
<td>V</td>
</tr>
<tr>
<td>I_F</td>
<td>continuous forward current</td>
<td>–</td>
<td>20</td>
<td>mA</td>
</tr>
<tr>
<td>T_stg</td>
<td>storage temperature</td>
<td>–55</td>
<td>+150</td>
<td>°C</td>
</tr>
<tr>
<td>T_j</td>
<td>operating junction temperature</td>
<td>–55</td>
<td>+125</td>
<td>°C</td>
</tr>
</tbody>
</table>

ELECTRICAL CHARACTERISTICS

T_j = 25 °C; unless otherwise specified.

<table>
<thead>
<tr>
<th>SYMBOL</th>
<th>PARAMETER</th>
<th>CONDITIONS</th>
<th>MIN.</th>
<th>TYP.</th>
<th>MAX.</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>I_R</td>
<td>reverse current</td>
<td>V_R = 28 V; see Fig.3</td>
<td>–</td>
<td>–</td>
<td>10</td>
<td>nA</td>
</tr>
<tr>
<td></td>
<td></td>
<td>V_R = 28 V; T_j = 85 °C; see Fig.3</td>
<td>–</td>
<td>–</td>
<td>200</td>
<td>nA</td>
</tr>
<tr>
<td>r_s</td>
<td>diode series resistance</td>
<td>f = 100 MHz; note 1</td>
<td>–</td>
<td>–</td>
<td>3</td>
<td>Ω</td>
</tr>
<tr>
<td>C_d</td>
<td>diode capacitance</td>
<td>V_R = 28 V; f = 1 MHz; see Figs 2 and 4</td>
<td>–</td>
<td>–</td>
<td>1.055</td>
<td>pF</td>
</tr>
<tr>
<td>C_d(0.5V)/C_d(28V)</td>
<td>capacitance ratio</td>
<td>f = 1 MHz</td>
<td>12</td>
<td>–</td>
<td>–</td>
<td></td>
</tr>
</tbody>
</table>

Note

1. V_R is the value at which C_d = 10 pF.
VHF variable capacitance diode

BB901

GRAPHICAL DATA

Fig. 2  Diode capacitance as a function of reverse voltage; typical values.

Fig. 3  Reverse current as a function of junction temperature; maximum values.

Fig. 4  Temperature coefficient of diode capacitance as a function of reverse voltage; typical values.

\[ f = 1 \text{ MHz; } T_j = 25 \text{ °C} \]
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PACKAGE OUTLINE

Dimensions in mm.

Fig.5  SOT23.

DEFINITIONS

Data sheet status

<table>
<thead>
<tr>
<th>Specification</th>
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<tr>
<td>Objective specification</td>
<td>This data sheet contains target or goal specifications for product development.</td>
</tr>
<tr>
<td>Preliminary specification</td>
<td>This data sheet contains preliminary data; supplementary data may be published later.</td>
</tr>
<tr>
<td>Product specification</td>
<td>This data sheet contains final product specifications.</td>
</tr>
</tbody>
</table>

Limiting values

Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

LIFE SUPPORT APPLICATIONS

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